



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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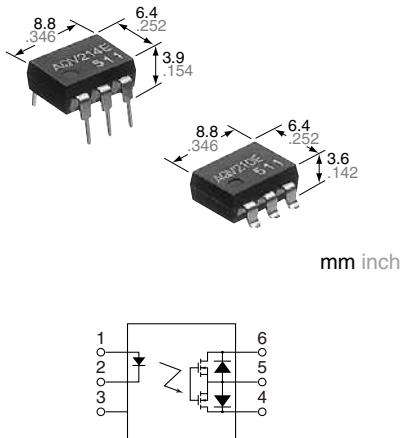
Standard type: Reinforced type:

DIP6-pin type, reinforced insulation available

PhotoMOS®

GE 1 Form A

(AQV210E, AQV210EH)



FEATURES

1. **Reinforced insulation of I/O isolation voltage 5,000V (Reinforced insulation type)**
2. **Controls low-level analog signals**
PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
3. **Stable on-resistance**
4. **Low-level off state leakage current of max. 1 μ A**

TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Data communication equipment
- Computers

RoHS compliant

TYPES

I/O isolation	Output rating*	Load voltage	Load current	Package	Part No.			Packing quantity
					Through hole terminal		Surface-mount terminal	
					Tube packing style		Tape and reel packing style	
AC/DC dual use	Standard 1,500 V AC	350 V	130 mA	DIP6-pin	AQV210E	AQV210EA	AQV210EAX	AQV210EAZ
		400 V	120 mA		AQV214E	AQV214EA	AQV214EAX	AQV214EAZ
	Reinforced 5,000 V	350 V	130 mA		AQV210EH	AQV210EHA	AQV210EHAX	AQV210EHAZ
		400 V	120 mA		AQV214EH	AQV214EHA	AQV214EHAX	AQV214EHAZ

*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

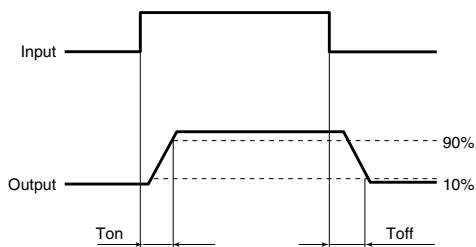
Item		Symbol	Type of connection	AQV210E(A)	AQV214E(A)	AQV210EH(A)	AQV214EH(A)	Remarks			
Input		I _F		50 mA		f = 100 Hz, Duty factor = 0.1%					
		V _R		5 V							
		I _{FP}		1 A							
		P _{in}		75 mW							
Output		V _L		350 V	400 V	350 V	400 V	A connection: Peak AC, DC B, C connection: DC			
		I _L		A	0.13 A	0.12 A	0.13 A				
				B	0.15 A	0.13 A	0.15 A				
				C	0.17 A	0.15 A	0.17 A				
Total power dissipation		P _T		0.4 A	0.3 A	0.4 A	0.3 A	A connection: 100 ms (1 shot), V _L =DC			
I/O isolation voltage		V _{iso}		500 mW		550 mW					
Temperature limits		Operating T _{opr}		1,500 V AC	5,000 V AC		Non-condensing at low temp.				
		Storage T _{stg}		-40°C to +85°C -40°F to +185°F		-40°C to +100°C -40°F to +212°F					

GE 1 Form A (AQV21OE, AQV21OEH)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	Type of connection	AQV210E(A)	AQV214E(A)	AQV210EH(A)	AQV214EH(A)	Condition
Input	LED operate current	Typical	I _{Fon}	—	1.1 mA		1.6 mA		I _L = Max.
		Maximum			3 mA				
	LED turn off current	Minimum	I _{loff}	—	0.3 mA		0.4 mA		I _L = Max.
		Typical			1.0 mA		1.5 mA		
	LED dropout voltage	Typical	V _F	—	1.25 V (1.14 V at I _F = 5 mA)				I _F = 50 mA
		Maximum			1.5 V				
Output	On resistance	Typical	R _{on}	A	23 Ω	30 Ω	23 Ω	30 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
		Maximum			35 Ω	50 Ω	35 Ω	50 Ω	
		Typical	R _{on}	B	11.5 Ω	22.5 Ω	11.5 Ω	22.5 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
		Maximum			17.5 Ω	25 Ω	17.5 Ω	25 Ω	
		Typical	R _{on}	C	6.0 Ω	11.3 Ω	6.0 Ω	11.3 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
		Maximum			8.8 Ω	12.5 Ω	8.8 Ω	12.5 Ω	
	Off state leakage current	Maximum	I _{Leak}	—	1 μA				I _F = 0 mA V _L = Max.
Transfer characteristics	Turn on time*	Typical	T _{on}	—	0.5 ms		0.7 ms		I _F = 5 mA I _L = Max.
		Maximum			2.0 ms				
	Turn off time*	Typical	T _{off}	—	0.05 ms		1.0 ms		I _F = 5 mA I _L = Max.
		Maximum			1.0 ms				
	I/O capacitance	Typical	C _{iso}	—	0.8 pF		f = 1 MHz		V _B = 0 V
		Maximum			1.5 pF				
	Initial I/O isolation resistance	Minimum	R _{iso}	—	1,000 MΩ				500 V DC

*Turn on/Turn off time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I _F	Standard type: 5 Reinforced type: 5 to 10	mA

■ These products are not designed for automotive use.

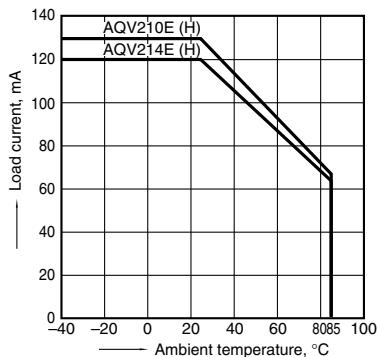
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

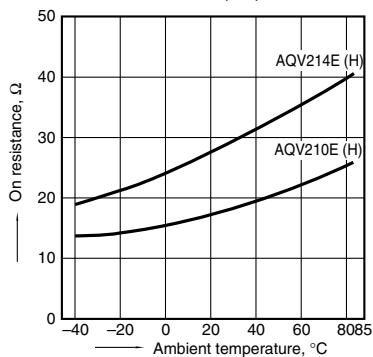
Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$
 -40°F to $+185^{\circ}\text{F}$

Type of connection:A



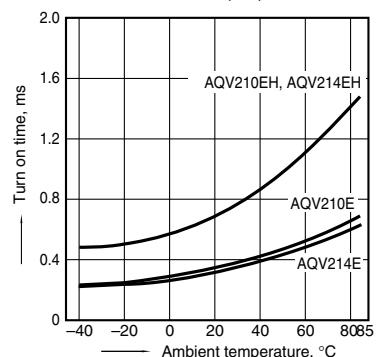
2. On-resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
 LED current: 5 mA; Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



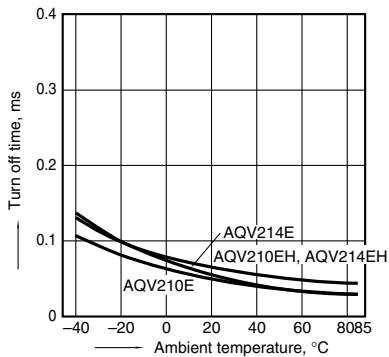
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA;
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



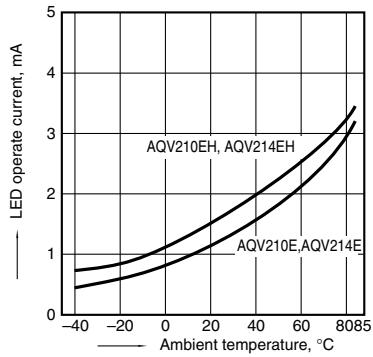
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



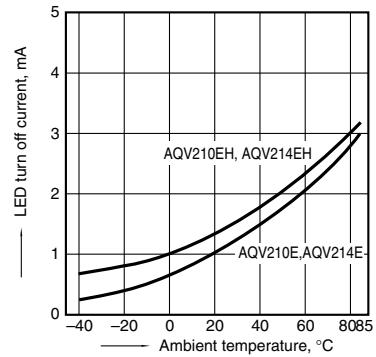
5. LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



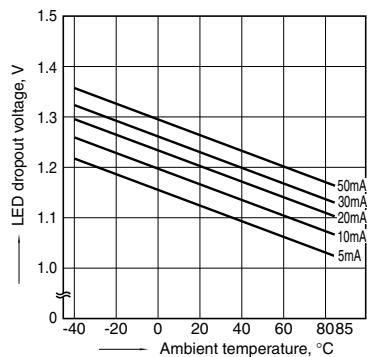
6. LED turn off current vs. ambient temperature characteristics

Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



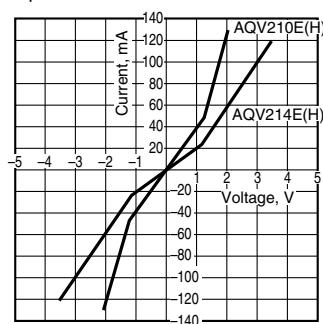
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types
 LED current: 5 to 50 mA



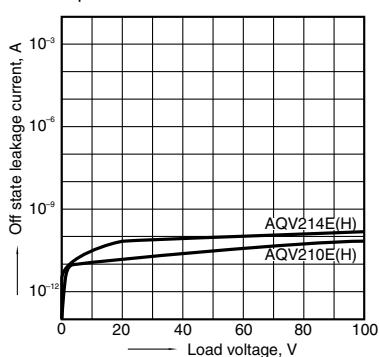
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



9. Off state leakage current vs. load voltage characteristics

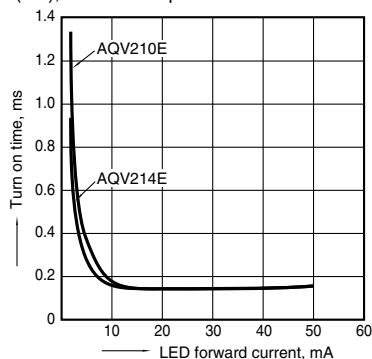
Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



GE 1 Form A (AQV210E, AQV210EH)

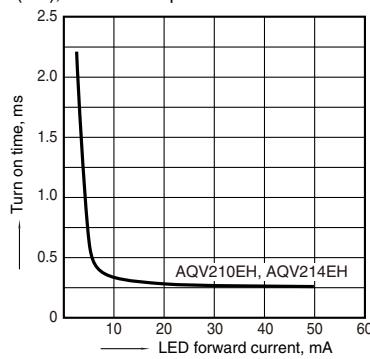
10-(1). Turn on time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



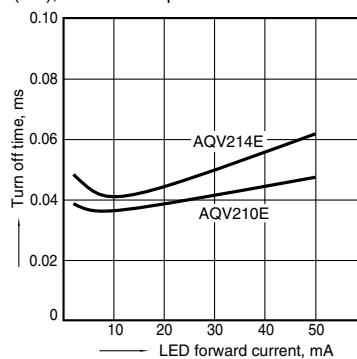
10-(2). Turn on time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



11-(1). Turn off time vs. LED forward current characteristics

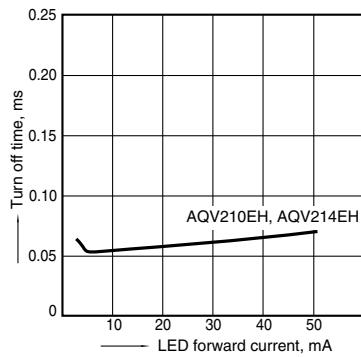
Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



11-(2). Turn off time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F

